## Kronig-Penney model

### Task 1

#### Given:

- a = 1.5 Å (well width)
- b = 1.0 Å (barrier width)
- V(x) varies from 0 to 10 eV.

**Model:** Kronig–Penney model (delta-function limit when  $b \to 0$  but here b fixed, finite rectangular barriers).

The band gap width between 1st and 2nd bands depends on the strength of the periodic potential.

Approximate gap formula (for delta-potential version):

$$V_0 b = P(\text{strength}), E_q \approx 2 \mid V_G \mid$$

where  $V_G$  is the Fourier component of potential for reciprocal vector  $G = 2\pi/(a+b)$ . For finite rectangular barriers, the gap at  $k = \pi/(a+b)$  (BZ boundary) increases with  $V_0$ .

### **Trend:**

- When  $V_0 = 0$ , free electron  $\rightarrow$  no gap.
- As  $V_0$  increases, gap increases monotonically, saturating slowly.

# Rough plot description:

- x-axis:  $V_0$  (eV)
- y-axis: Band gap  $E_g$  (eV)
- Curve: Starts at (0,0), rises sharply for small  $V_0$ , then increases more slowly toward saturation.

 $E_a(V_0) \propto \text{ something like} 2\sqrt{V_0 E_1} \text{ initially, then linear? Actually from KP equation:}$ 

KP equation:

$$\cos(ka) = \cos(k_1 a) + P \frac{\sin(k_1 a)}{k_1 a}, P$$

$$= \frac{mV_0 ba}{\hbar^2}$$
 (in some units)

Gap occurs when | RHS |> 1 is not possible  $\rightarrow$  gap width  $\Delta \approx 2V_0 \frac{\sin{(\pi a/(a+b))}}{\pi}$  for small  $V_0$ ? Actually, known:

For delta-barrier:  $E_g \approx 2V_0b/a$  for small P, but here b fixed, so  $E_g \propto V_0$  initially.

Conclusion for plot: Linear rise for small  $V_0$ , then sublinear, saturating.

### Task 2

#### Given:

- $a = 1.5 \,\text{Å}$
- $V_0 = 5 \text{ eV}$
- Vary barrier width b.

**Effect:** Increasing *b* increases the "duty cycle" of the barrier, increasing the effective potential strength.

In delta limit  $(b \to 0)$ ,  $P = mV_0ba/\hbar^2 \to \text{gap}$  proportional to  $P \to \text{proportional}$  to b. For finite b, the Fourier component  $V_G$  is:

$$V_{G} = \frac{1}{a+b} \int_{0}^{b} V_{0}e^{-iGx}dx, G = 2\pi/(a+b)$$

$$|V_{G}| = \frac{V_{0}}{a+b} |\frac{1-e^{-iGb}}{iG}| = \frac{V_{0}}{a+b} \cdot \frac{2|\sin(Gb/2)|}{G}$$

So  $E_g \propto |V_G| \propto \frac{\sin(\pi b/(a+b))}{\pi/(a+b)}$ .

Thus  $E_g(b)$  increases from b=0 to a maximum at b/(a+b)=0.5 (when  $\sin (\pi b/(a+b))=1$ ), then decreases to 0 when b=a+b (all barrier, no well  $\to$  no gap? Actually period changes). But physically, when b increases too much, the bands become flat, but gap max at  $b\approx a$ .

# Rough plot:

- x-axis: b (Å) from 0 to ~3 Å
- y-axis:  $E_q$
- Curve: Starts at 0 for b=0, peaks around  $b\approx a=1.5$  Å, then decreases toward 0 as  $b\to\infty$  (infinite barrier  $\to$  isolated wells  $\to$  degenerate levels  $\to$  gap between bands? Actually gap between ground and first excited state in a well remains, but in periodic model, when b large, tunneling negligible, band width  $\sim$ 0, gap  $\sim$  fixed? Need care.)

Actually in KP model, as b increases with a fixed, potential becomes more like a square well array: gap between bands approaches the difference between quantized levels in a single well of width a. So gap saturates, not goes to 0. My earlier sine-form wrong for large b.

Better: For large b,  $E_g \rightarrow E_2 - E_1$  of a well of size a, independent of b. So plot: increase, then saturate.

#### Task 3

Amorphous solid lacks long-range order but has short-range order (similar atomic spacing). From Tasks 1 and 2:

Gap depends on potential strength (related to atomic potential — chemical composition) and spatial width of potential barrier/well (related to atomic spacing and atomic size).

In amorphous solid:

- Well depth  $V_0 \rightarrow$  determined by atomic nuclear charge and screening  $\rightarrow$  chemical element.
- Well width  $a \rightarrow$  related to nearest-neighbor distance (short-range order).

Thus, even without periodicity, if the short-range potential is similar to crystalline case (same atom type and bond length), the band gap can persist because the gap originates from the strong potential scattering at  $k \approx \pi$ /interatomic spacing, which exists in amorphous phase due to retention of short-range order.

**Conclusion:** Key short-range properties:

- 1. Atomic potential strength (atomic number)
- 2. Nearest-neighbor distance (well width)
- 3. Coordination (affects potential shape)

Example: SiO₂ amorphous: Si–O bond length and strong ionic potential → large gap ~9 eV.

#### Task 4

Bragg law:  $2d\sin \theta = n\lambda$ .

For electrons in crystal:  $\lambda = 2\pi/k$ , Bragg condition  $\rightarrow k = n\pi/d$ .

At BZ boundary  $k = \pi/d$ , electrons satisfy Bragg condition  $\rightarrow$  strong reflection  $\rightarrow$  standing waves  $\rightarrow$  band gap.

Electrons with k far from BZ boundary propagate freely (no Bragg reflection).

## Crystal effect for other k:

- For k not near BZ boundary, nearly free electron behavior.
- Crystal potential causes **band curvature** (effective mass changes) due to E(k) deviation from parabola.
- Also, for k near BZ center, small periodic perturbation  $\rightarrow$  slightly lowered energy compared to free electron.

#### Task 5

Empty lattice model: V = 0, but impose periodicity — fold free electron dispersion into reduced zone scheme.

1D lattice period a.

Free electron:  $E(k) = \frac{\hbar^2 k^2}{2m}$ .

Reduced zone scheme: For any k in first BZ  $(-\pi/a, \pi/a]$ ,

$$E_n(k) = \frac{\hbar^2}{2m} (k + \frac{2\pi n}{a})^2, n = 0, \pm 1, \pm 2, \dots$$

First three bands  $(n = 0, \pm 1)$ :

- n = 0:  $E_0(k) = \frac{\hbar^2 k^2}{2m}$  parabola centered at k = 0.
- n=-1:  $E_{-1}(k)=\frac{\hbar^2}{2m}(k-\frac{2\pi}{a})^2$  in 1BZ, shift equivalent to  $k+2\pi/a\to$  actually  $k-2\pi/a$  mapped to k in 1BZ: Let  $k'=k-2\pi/a$ , in 1BZ k' is  $k-2\pi/a$  if k>0 small? Better:

Actually n=-1:  $k-2\pi/a \to \text{in reduced zone}$ , use  $k-2\pi/a=k-G$  with  $G=2\pi/a$ , so  $E(k)=\frac{\hbar^2}{2m}(k-2\pi/a)^2$ , but for k in 1BZ, plot that.

Better: Explicit:

Let  $G = 2\pi/a$ .

Band 1 (n = 0):  $E = \frac{\hbar^2 k^2}{2m}$ , minimum 0 at k = 0.

Band 2 
$$(n=-1)$$
:  $E=\frac{\hbar^2(k-G)^2}{2m}$ . In 1BZ, at  $k=-\pi/a$ ,  $k-G=-\pi/a-2\pi/a=-3\pi/a$ ,  $E=\frac{\hbar^2(9\pi^2/a^2)}{2m}$ . At  $k=\pi/a$ ,  $k-G=\pi/a-2\pi/a=-\pi/a$ ,  $E=\frac{\hbar^2\pi^2/a^2}{2m}$ . So it's a parabola decreasing from  $k=-\pi/a$  to  $k=\pi/a$ .

Band 3 
$$(n = 1)$$
:  $E = \frac{\hbar^2 (k+G)^2}{2m}$ . At  $k = -\pi/a$ ,  $k + G = \pi/a$ ,  $E = \frac{\hbar^2 \pi^2/a^2}{2m}$ . At  $k = \pi/a$ ,  $k + G = 3\pi/a$ ,  $E = \frac{\hbar^2 9\pi^2/a^2}{2m}$ , so increasing parabola.

#### Wavefunction:

$$\psi_{nk}(x) = e^{ikx}u_{nk}(x), u_{nk}(x) = \operatorname{const} \cdot e^{iG_n x}, G_n = n \frac{2\pi}{a}.$$

So  $\psi_{nk}(x) \propto e^{i(k+G_n)x}$  — plane wave.

**Plot:** In 1BZ, three bands:

- n=0: upward parabola from 0 at k=0 to  $\hbar^2(\pi/a)^2/2m$  at edges.
- n=-1: symmetric with n=1 actually degenerate at BZ boundary. Actually at  $k = \pi/a$ , n=-1 and n=1 both have  $E = \hbar^2 (\pi/a)^2 / 2m$ . At k = 0, n=-1:  $E = \hbar^2 (2\pi/a)^2 / 2m$ , n=1 same. So band 2 and 3 are degenerate at center and boundaries? Wait, check:

At k = 0:

n=-1: 
$$E = (-2\pi/a)^2 = 4\pi^2/a^2$$
 times  $\hbar^2/2m$ 

n=1: same.

So bands 2 and 3 are degenerate everywhere? No, because at k nonzero, (k+G) and (k-G) magnitudes differ unless k=0. Actually they're degenerate only at k=0.

So bands:

Band 1: bottom 0 at k=0

Band 2 & 3: both start at  $4\pi^2\hbar^2/2ma^2$  at k=0, then one decreases to  $\pi^2\hbar^2/2ma^2$  at k= $\pi/a$  (n=-1), the other increases to  $9\pi^2\hbar^2/2ma^2$  at k= $\pi/a$  (n=1). So they cross. In empty lattice, no gap at crossing.

#### Task 6

2D square lattice, lattice constant a.

Reciprocal lattice vectors:  $\mathbf{G} = (m, n) \frac{2\pi}{a}$ .

Path X to M:

X point:  $(\pi/a, 0)$ 

M point:  $(\pi/a, \pi/a)$ 

So we vary  $k_y$  from 0 to  $\pi/a$ , keeping  $k_x = \pi/a$ .

Empty lattice bands:

$$E(\mathbf{k}) = \frac{\hbar^2}{2m} |\mathbf{k} + \mathbf{G}|^2$$

with  $\mathbf{k} = (\pi/a, k_v)$ .

Choose small **G** values:

$$\mathbf{G} = (0,0), (\pm 1,0), (0,\pm 1), (\pm 1,\pm 1), (-1,1), (1,-1) \text{ etc.}$$

Compute for each:

1. 
$$G = (0,0)$$
:

$$\mathbf{k} + \mathbf{G} = (\pi/a, k_v)$$

$$E = \frac{\hbar^2}{2m} [(\pi/\alpha)^2 + k_y^2]$$
 — increases with  $k_y$ .

2. 
$$G = (-1,0) \cdot 2\pi/a = (-2\pi/a, 0)$$
:

$$\mathbf{k} + \mathbf{G} = (\pi/a - 2\pi/a, k_v) = (-\pi/a, k_v)$$

Same magnitude as above  $\rightarrow$  degenerate with G=(0,0) band.

3. 
$$G = (0, -1) \cdot 2\pi/a = (0, -2\pi/a)$$
:

$$\mathbf{k} + \mathbf{G} = (\pi/a, k_v - 2\pi/a)$$

Magnitude:  $(\pi/a)^2 + (k_y - 2\pi/a)^2$  — large at  $k_y = 0$ , min at  $k_y = 2\pi/a$  outside range.

4. 
$$G = (-1, -1) \cdot 2\pi/\alpha = (-2\pi/\alpha, -2\pi/\alpha)$$
:

$$\mathbf{k} + \mathbf{G} = (-\pi/a, k_y - 2\pi/a)$$
 magnitude same as above case symmetric.

Better to list few lowest at  $k_v = 0$  (X point):

At X:  $k_x = \pi/a$ ,  $k_y = 0$ :

- G=(0,0):  $E = (\pi/a)^2$  in units  $\hbar^2/2m$ .
- G=(-1,0): same as above.
- G=(0,-1):  $(\pi/a)^2 + (2\pi/a)^2 = 5(\pi/a)^2$
- G=(-1,-1): same 5.
- G=(1,0):  $(3\pi/a)^2 = 9$
- G=(0,1):  $(\pi/a)^2 + (2\pi/a)^2 = 5$  again.

So lowest band: doubly degenerate E=1 unit at X.

As  $k_v$  increases, these bands disperse.

We can plot E vs  $k_v$  from 0 to  $\pi/a$  for these G's.

#### **Bands:**

Band1: G=(0,0) & (-1,0) degenerate:  $E = 1 + k_y^2$  in units of  $(\pi/a)^2\hbar^2/2m$ .

Band2: G=(0,-1) & (-1,-1):  $E = 1 + (k_y - 2)^2$  but 2 in units of  $\pi/a$ , so at  $k_y = 0$ , E=1+4=5,

at  $k_y = 1$ , E=1+1=2, at  $k_y = 1$  (M point), E=2.

Band3: G=(1,0):  $E = (3)^2 + k_y^2 = 9 + k_y^2$  — high.

Band4: G=(0,1):  $E = 1 + (k_y + 2)^2$  at  $k_y = 0$ , E=5, increases.

Band5: G=(1,1):  $E = (3)^2 + (k_y + 2)^2$  very high.

So five lowest bands: two low ones (degenerate), then next at E=5 at X, splitting with  $k_y$ .

Plot: E vs  $k_v$  from 0 to 1 (in units of  $\pi/a$ ), energies in units of  $(\pi^2 \hbar^2)/(2ma^2)$ .